NSN 5961-01-080-8165

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-080-8165 **Inclosure Material:** Metal and ceramic **Overall Length:** 0.292 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc **Current Rating Per Characteristic:** 5.00 amperes all primaries preset **Power Rating Per Characteristic:** 18.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unc **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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